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N-Channel 200 V (D-S) MOSFET

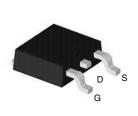
PRODUCT SUMMARY					
V _{DS} (V)	$R_{DS(on)}(\Omega)$				
200	0.048 at V _{GS} = 10 V	30			

FEATURES

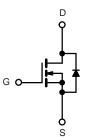
- DT-Trench Power MOSFET
- 175 °C Junction Temperature
- PWM Optimized
- 100 % R_a Tested
- Compliant to RoHS Directive 2002/95/EC



TO-252 Pin Configuration







N-Channel MOSFET

APPLICATIONS

· Primary Side Switch

ABSOLUTE MAXIMUM RATINGS (T _A = 25 °C, unless otherwise noted)						
Parameter		Symbol	Limit	Unit		
Drain-Source Voltage		V _{DS}	200	V		
Gate-Source Voltage	V_{GS}	± 20	v			
Continuous Proje Coment /T 475 90\b	T _C = 25 °C	L	30			
Continuous Drain Current (T _J = 175 °C) ^b	T _C = 125 °C	I _D	21			
Pulsed Drain Current	I _{DM}	120	А			
Continuous Source Current (Diode Conduction)	I _S	29				
Avalanche Current	I _{AS}	29				
Single Pulse Avalanche Energy	L = 0.1 mH	E _{AS}	18	mJ		
Mayimum Dayyar Dissination	T _C = 25 °C	P _D	136 ^b	W		
Maximum Power Dissipation	T _A = 25 °C	T D	3 ^a	_ vv		
Operating Junction and Storage Temperature Range	•	T _J , T _{stg}	- 55 to 175	°C		

THERMAL RESISTANCE RATINGS							
Parameter		Symbol	Typical	Maximum	Unit		
hungation to Ambienti	t ≤ 10 s	- R _{thJA}	15	18	°C/W		
Junction-to-Ambient ^a	Steady State		40	50			
Junction-to-Case (Drain)	•	R _{thJC}	0.85	1.1			

Notes:

- a. Surface mounted on 1" x 1" FR4 board.
- b. See SOA curve for voltage derating.

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Parameter Symbol		Test Conditions	Min.	Typ. ^a	Max.	Unit	
Static							
Drain-Source Breakdown Voltage	V _{DS}	$V_{GS} = 0 \text{ V}, I_D = 250 \mu\text{A}$	200			V	
Gate Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}, I_{D} = 250 \mu A$	2		4	V	
Gate-Body Leakage	I _{GSS}	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 20 \text{ V}$			± 100	nA	
		V _{DS} = 160 V, V _{GS} = 0 V			1		
Zero Gate Voltage Drain Current	I_{DSS}	V _{DS} = 160 V, V _{GS} = 0 V, T _J = 125 °C			50	, I	
		V _{DS} = 160 V, V _{GS} = 0 V, T _J = 175 °C			250		
On-State Drain Current ^b	I _{D(on)}	$V_{DS} = 5 \text{ V}, V_{GS} = 10 \text{ V}$	30			Α	
		$V_{GS} = 10 \text{ V}, I_{D} = 20 \text{ A}$		0.048 0.060			
Danier Courses On Chata Desistance	R	V _{GS} = 10 V, I _D = 5 A, T _J = 125 °C			0.065		
Drain-Source On-State Resistance ^D	R _{DS(on)}	$V_{GS} = 10 \text{ V}, I_D = 5 \text{ A}, T_J = 175 °C$			0.076	Ω	
		$V_{GS} = 6 \text{ V}, I_D = 10 \text{ A}$		0.055	0.070		
Forward Transconductance ^b	9 _{fs}	V _{DS} = 15 V, I _D = 20 A		35		S	
Dynamic ^a							
Input Capacitance	C _{iss}			1800		pF	
Output Capacitance	C _{oss}	$V_{GS} = 0 \text{ V}, V_{DS} = 25 \text{ V}, F = 1 \text{ MHz}$		180			
Reverse Transfer Capacitance	C _{rss}			80			
Total Gate Charge ^c	Q_g			34	51		
Gate-Source Charge ^c	Q_{gs}	$V_{DS} = 100 \text{ V}, V_{GS} = 10 \text{ V}, I_{D} = 20 \text{ A}$		8		nC	
Gate-Drain Charge ^c	Q_{gd}			12			
Gate Resistance	R_g		0.5		2.9	Ω	
Turn-On Delay Time ^c	t _{d(on)}			15	25		
Rise Time ^c	t _r	$V_{DD} = 100 \text{ V}, R_{L} = 5.2 \Omega$		50	75	ns	
Turn-Off Delay Time ^c	t _{d(off)}	$I_D \cong 20 \text{ A}, V_{GEN} = 10 \text{ V}, R_g = 2.5 \Omega$		30	45		
Fall Time ^c	t _f			60	90		
Source-Drain Diode Ratings and Char	acteristics (7	_C = 25 °C)					
Pulsed Current	I _{SM}				120	Α	
Diode Forward Voltage ^b	V_{SD}	I _F = 19 A, V _{GS} = 0 V		0.9	1.5	V	
Source-Drain Reverse Recovery Time	t _{rr}	I _F = 19 A, dl/dt = 100 A/μs		180	250	ns	

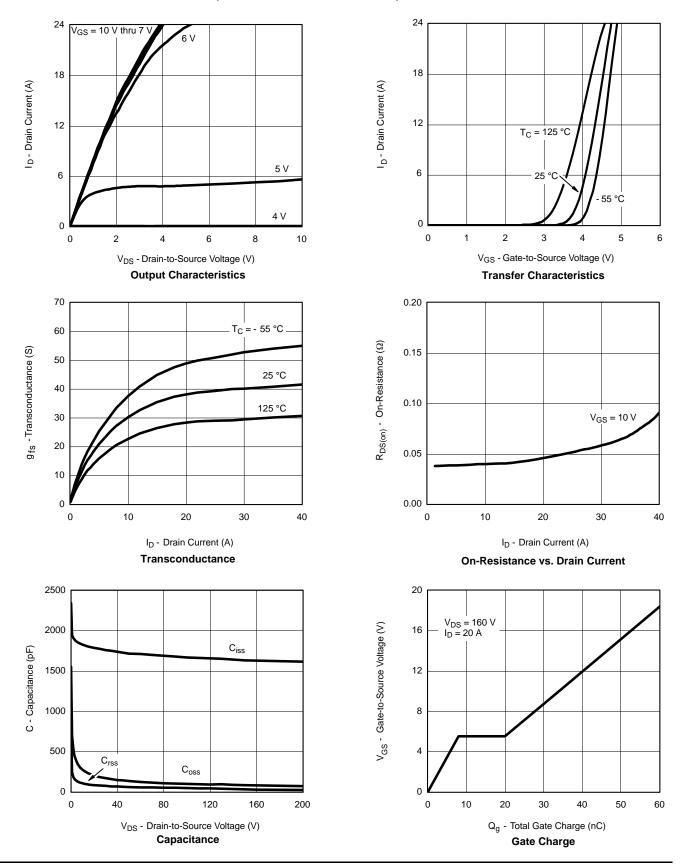
Notes:

- a. Guaranteed by design, not subject to production testing.
- b. Pulse test; pulse width \leq 300 μ s, duty cycle \leq 2 %.
- c. Independent of operating temperature.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

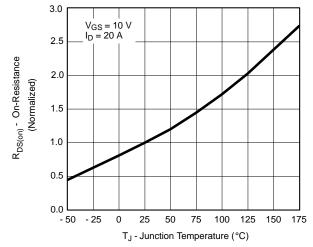


TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



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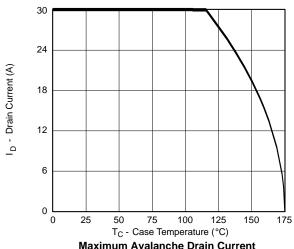


On-Resistance vs. Junction Temperature

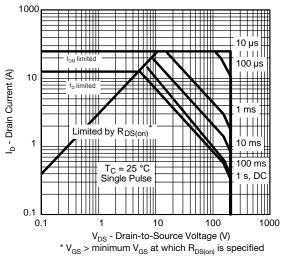
$T_{J} = 150 \, ^{\circ}\text{C}$ $T_{J} = 25 \, ^{\circ}\text{C}$ $V_{SD} - \text{Source-to-Drain Voltage (V)}$

Source-Drain Diode Forward Voltage

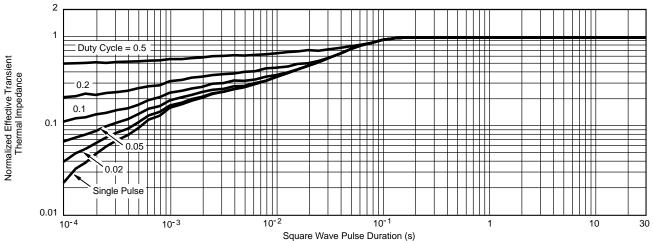
THERMAL RATINGS



Maximum Avalanche Drain Current vs. Case Temperature



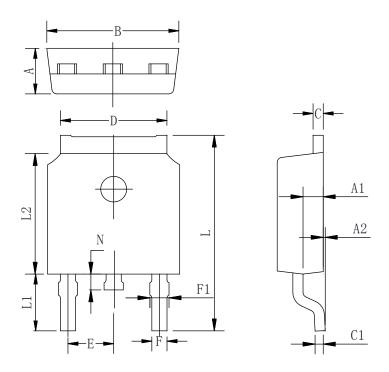
Safe Operating Area



Normalized Thermal Transient Impedance, Junction-to-Case



TO-252-2L PACKAGE OUTLINE



COMMON DIMENSIONS (UNITS OF MEASURE=MILLIMETER)

Symbol	Min	Тур	Max		
A	2.10	2.30	2.50		
A1	0.88	1.01	1.16		
A2	0.00	0.15	0.28		
В	6.40	6.60	6.80		
С	0.42	0.50	0.63		
C1	0.42	0.50	0.63		
D	5.08	5.32	5.65		
Е	2.286 TYP				
F	0.63	0.76	0.89		
F1	0.64	0.86	1.08		
L	9.30	9.90	10.80		
L1	2.4	2.8	3.6		
L2	5.90	6.10	6.55		
N	0.57	0.80	1.05		





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